



High Current Density Surface Mount Ultrafast Rectifiers

eSMP® Series



DO-220AA (SMP)

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	1.0 A
V_{RRM}	100 V, 150 V, 200 V
t_{rr}	15 ns
V_F	0.92 V
T_J max.	150 °C

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/DC and DC/DC converters for both consumer and automotive applications.

FEATURES

- Very low profile - typical height of 1.0 mm
- Ideal for automated placement
- Glass passivated chip junction
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power losses
- Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	ES1PB	ES1PC	ES1PD	UNIT
Device marking code		EB	EC	ED	
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	1.0			A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	30			A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150			°C

ES1PB, ES1PC, ES1PD

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage	$I_F = 0.6\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_F^{(1)}$	0.865	V
	$I_F = 1\text{ A}$			0.920	
Maximum reverse current at rated V_R		$T_J = 25\text{ }^{\circ}\text{C}$	$I_R^{(2)}$	5.0	μA
		$T_J = 125\text{ }^{\circ}\text{C}$		500	
Maximum reverse recovery time	$I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$		t_{rr}	15	ns
Typical reverse recovery time	$I_F = 1.0\text{ A}$, $V_R = 30\text{ V}$, $di/dt = 50\text{ A}/\mu\text{s}$, $I_{rr} = 10\% I_{RM}$	$T_J = 25\text{ }^{\circ}\text{C}$	t_{rr}	25	ns
		$T_J = 100\text{ }^{\circ}\text{C}$		30	
Typical stored charge	$I_F = 1.0\text{ A}$, $V_R = 30\text{ V}$, $di/dt = 50\text{ A}/\mu\text{s}$, $I_{rr} = 10\% I_{RM}$	$T_J = 25\text{ }^{\circ}\text{C}$	Q_{rr}	8	nC
		$T_J = 100\text{ }^{\circ}\text{C}$		10	
Typical junction capacitance	4.0 V, 1 MHz		C_J	10	pF

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ES1PB	ES1PC	ES1PD	UNIT
Typical thermal resistance	R _{θJA} ⁽¹⁾	105			°C/W
	R _{θJL} ⁽¹⁾	15			
	R _{θJC} ⁽¹⁾	20			

Note

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 mm x 5.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ES1PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel
ES1PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel
ES1PBHM3/84A ⁽¹⁾	0.024	84A	3000	7" diameter plastic tape and reel
ES1PBHM3/85A ⁽¹⁾	0.024	85A	10 000	13" diameter plastic tape and reel

Note

(1) Automotive grade



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

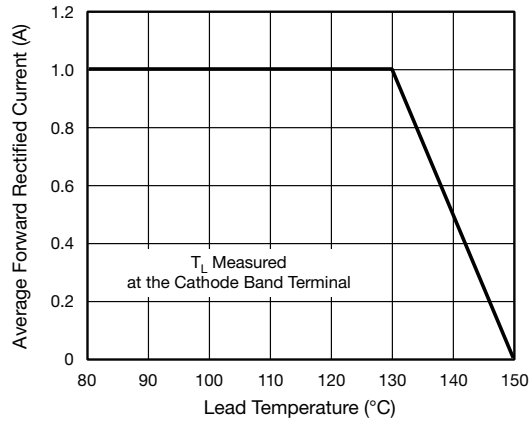


Fig. 1 - Maximum Forward Current Derating Curve

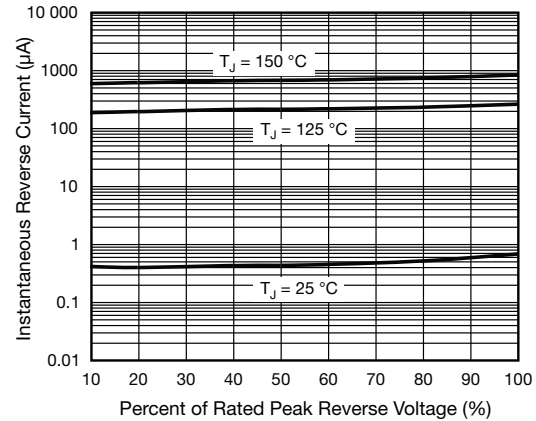


Fig. 4 - Typical Reverse Leakage Characteristics

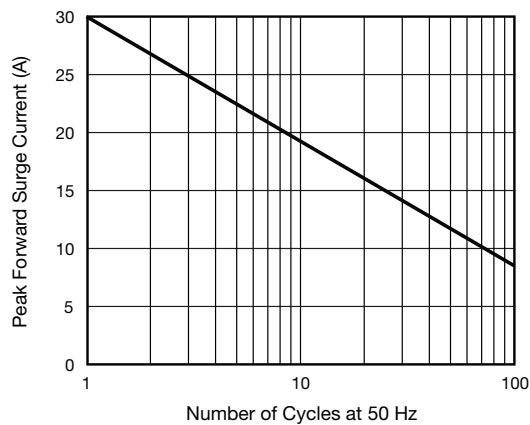


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

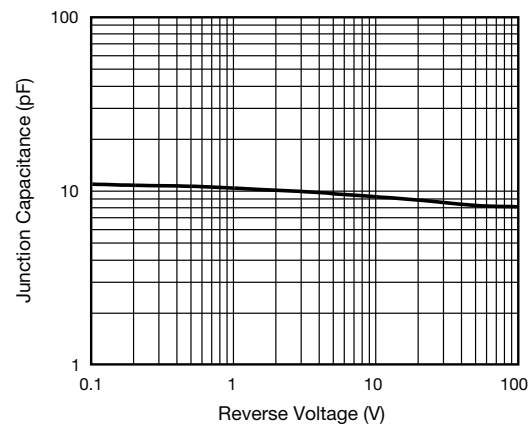


Fig. 5 - Typical Junction Capacitance

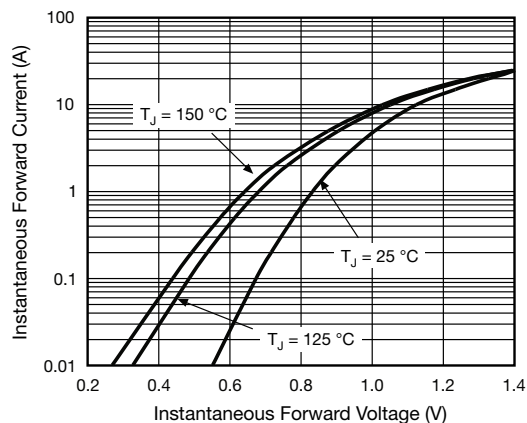


Fig. 3 - Typical Instantaneous Forward Characteristics

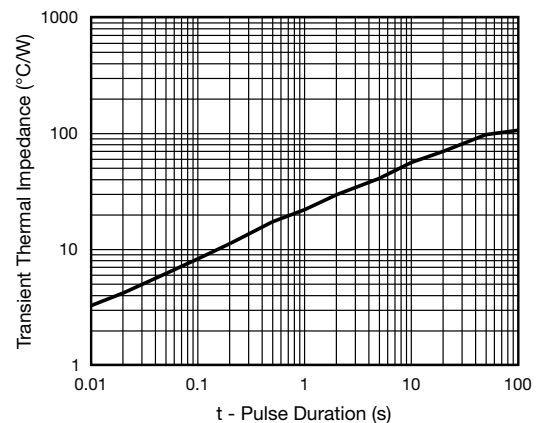
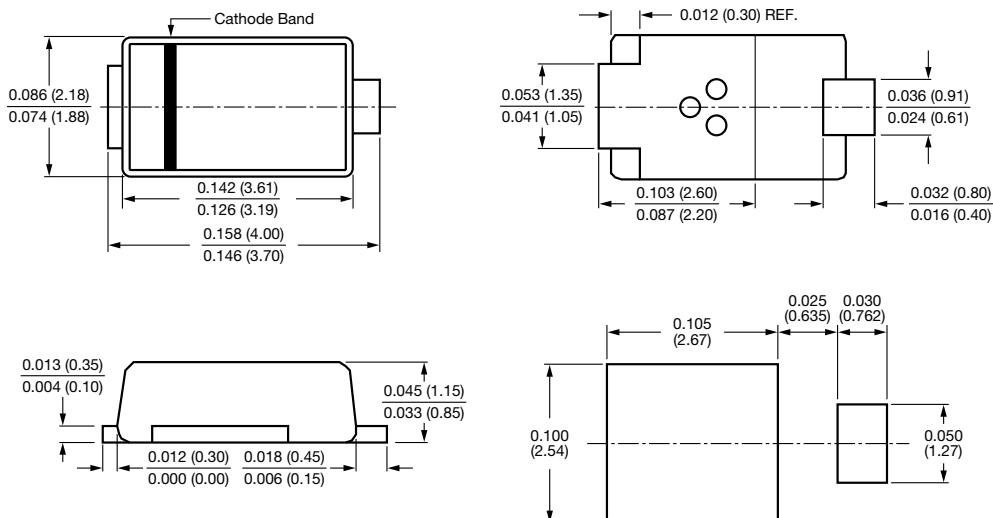


Fig. 6 - Typical Transient Thermal Impedance

ES1PB, ES1PC, ES1PD

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**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)
DO-220AA (SMP)



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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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